

Standard Silicon Rectifiers

Reverse Voltage - 100 to 1000 V

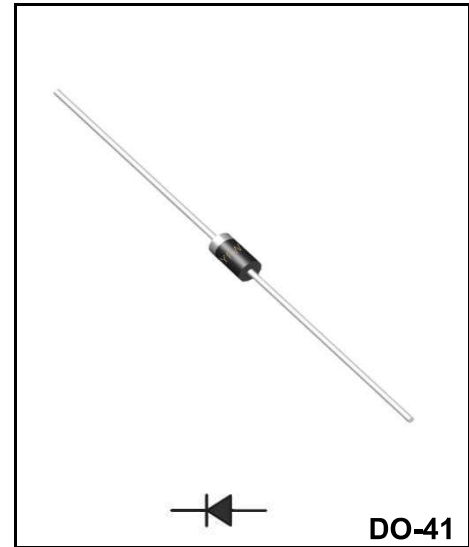
Forward Current - 1 A

FEATURES

- ◆For surface mounted applications
- ◆Low profile package
- ◆Glass passivated Junction chip
- ◆High forward surge current capability
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: DO-41
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 0.25g / 0.0088oz



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	1N4002G	1N4003G	1N4004G	1N4005G	1N4006G	1N4007G	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_c = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	1.0						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	30.0						A
Maximum Instantaneous Forward Voltage at 1.0A	V_F	1.0						V
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^\circ\text{C}$	I_R	5.0 50.0						μA
Typical Junction Capacitance ⁽¹⁾	C_j	15.0						pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	50.0						$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	-65 ~ +150						$^\circ\text{C}$

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

FIG. 1- DERATING CURVE OUTPUT RECTIFIED CURRENT

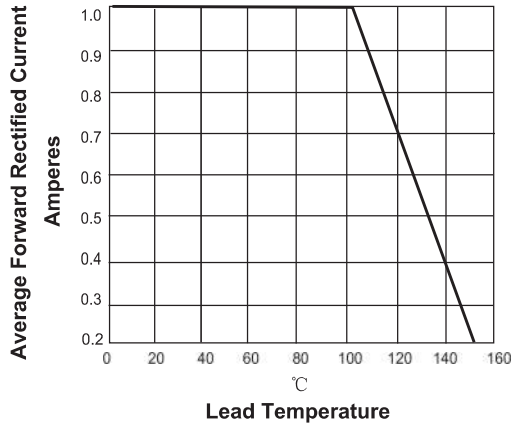


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

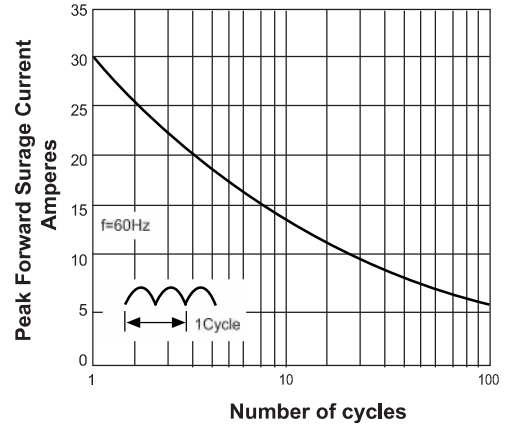


FIG. 3-TYPICAL FORWARD VOLTAGE CHARACTERISTICS

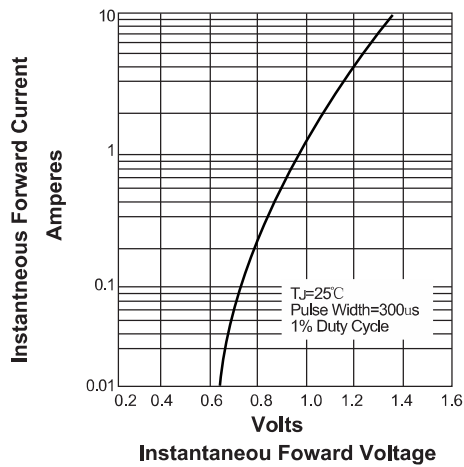
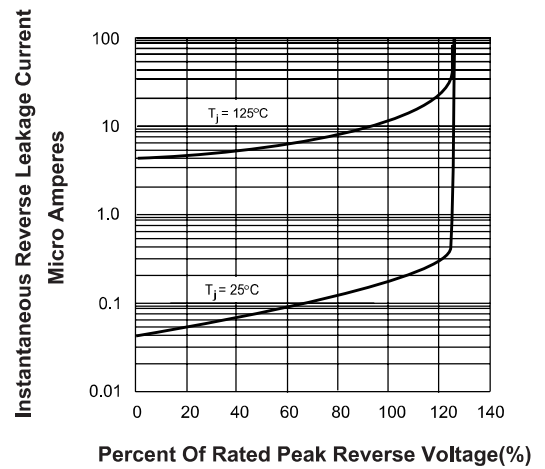


FIG. 4-TYPICAL REVERSE LEAKAGE CHARACTERISTICS



Ordering information

Package	Packing Description	Packing Quantity
DO-41	bulk	1000PCS/Inner Box 25000PCS/Carton
	ammo pack	5000PCS/Inner Box 50000PCS/Carton

Package Dimensions

DO-41

Dim.	Millimeter(mm)		INCHES	
	Min.	Max.	Min.	Max.
A	4.10	5.20	0.166	0.205
B	2.00	2.70	0.080	0.107
C	0.60	0.70	0.024	0.028
D	25.4	-	1.00	-

Disclaimer

The information presented in this document is for reference only. Guangdong Youfeng Microelectronics Co.,Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise. The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), YFW or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale. This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <https://www.yfwdiode.com>, or consult YFW sales office for further assistance.